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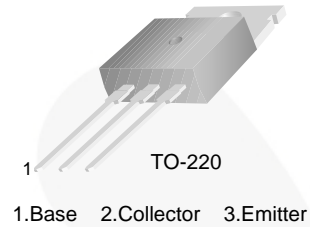


November 2014

FJP13007 High Voltage Fast-Switching NPN Power Transistor

Features

- High Voltage High Speed Power Switch Application
- High Voltage Capability
- High Switching Speed
- Suitable for Electronic Ballast and Switching Mode Power Supply



Ordering Information

Part Number	Top Mark	Package	Packing Method
FJP13007TU	J13007	TO-220 3L (Dual Gauge)	Rail
FJP13007H1TU	J13007-1	TO-220 3L (Single Gauge)	Rail
FJP13007H1TU_F080	J13007-1	TO-220 3L (Dual Gauge)	Rail
FJP13007H2TU	J13007-2	TO-220 3L (Dual Gauge)	Rail
FJP13007H2TU_F080	J13007-2	TO-220 3L (Dual Gauge)	Rail

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at $T_C = 25^\circ\text{C}$ unless otherwise noted.

Symbol	Parameter	Value	Unit
V_{CBO}	Collector-Base Voltage	700	V
V_{CEO}	Collector-Emitter Voltage	400	V
V_{EBO}	Emitter-Base Voltage	9	V
I_C	Collector Current (DC)	8	A
I_{CP}	Collector Current (Pulse)	16	A
I_B	Base Current (DC)	4	A
P_C	Collector Dissipation ($T_C = 25^\circ\text{C}$)	80	W
T_J	Junction Temperature	150	$^\circ\text{C}$
T_{STG}	Storage Temperature Range	-65 to 150	$^\circ\text{C}$

FJP13007 — High Voltage Fast-Switching NPN Power Transistor

Electrical Characteristics

Values are at $T_C = 25^\circ\text{C}$ unless otherwise noted.

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
BV_{CEO}	Collector-Emitter Breakdown Voltage	$I_C = 10\text{ mA}, I_B = 0$	400			V
I_{EBO}	Emitter Cut-Off Current	$V_{EB} = 9\text{ V}, I_C = 0$			1	mA
h_{FE1}	DC Current Gain ⁽¹⁾	$V_{CE} = 5\text{ V}, I_C = 2\text{ A}$	8		60	
h_{FE2}	DC Current Gain ⁽¹⁾	$V_{CE} = 5\text{ V}, I_C = 5\text{ A}$	5		30	
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	$I_C = 2\text{ A}, I_B = 0.4\text{ A}$			1.0	V
		$I_C = 5\text{ A}, I_B = 1\text{ A}$			2.0	
		$I_C = 8\text{ A}, I_B = 2\text{ A}$			3.0	
$V_{BE(sat)}$	Collector-Base Saturation Voltage	$I_C = 2\text{ A}, I_B = 0.4\text{ A}$			1.2	V
		$I_C = 5\text{ A}, I_B = 1\text{ A}$			1.6	
f_T	Current Gain Bandwidth Product	$V_{CE} = 10\text{ V}, I_C = 0.5\text{ A}$	4			MHz
C_{ob}	Output Capacitance	$V_{CB} = 10\text{ V}, f = 0.1\text{ MHz}$		110		pF
t_{ON}	Turn-On Time	$V_{CC} = 125\text{ V}, I_C = 5\text{ A},$ $I_{B1} = -I_{B2} = 1\text{ A},$ $R_L = 25\ \Omega$			1.6	μs
t_{STG}	Storage Time				3.0	μs
t_F	Fall Time				0.7	μs

Note:

1. Pulse test: $p_w \leq 300\ \mu\text{s}$, duty cycle $\leq 2\%$.

h_{FE} Classification

Classification	H1	H2
h_{FE1}	15 ~ 28	26 ~ 39

Typical Performance Characteristics

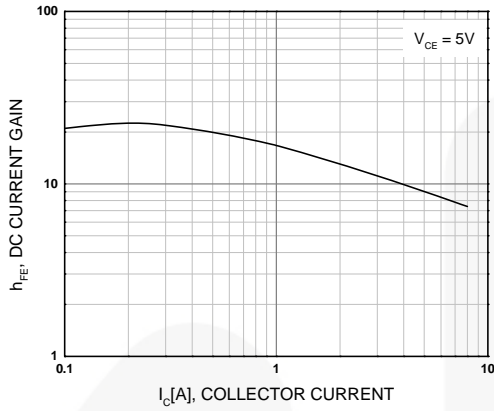


Figure 1. DC Current Gain

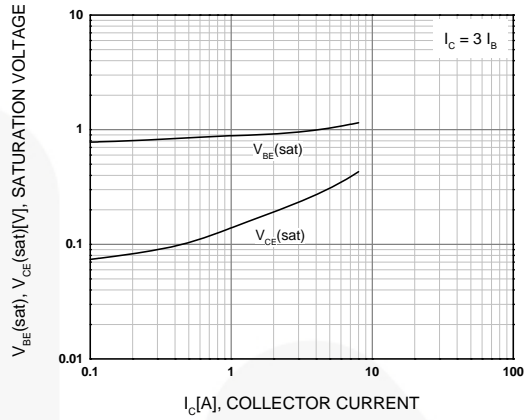


Figure 2. Saturation Voltage

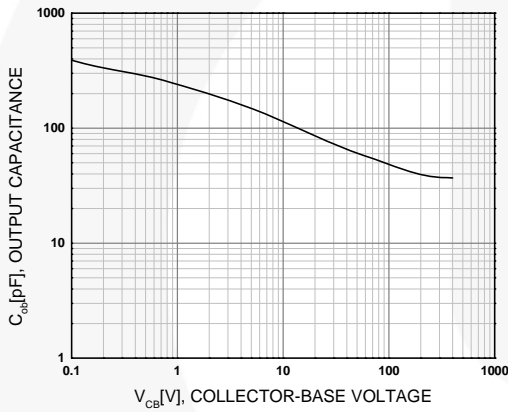


Figure 3. Collector Output Capacitance

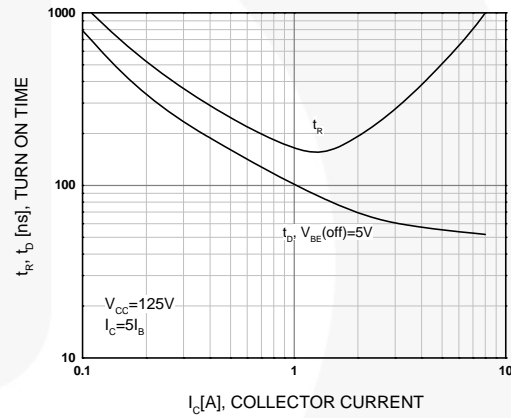


Figure 4. Turn-On Time

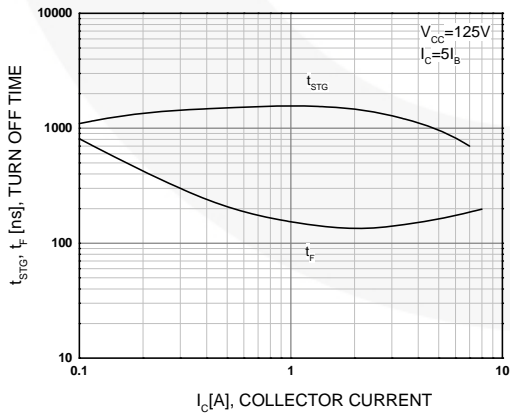


Figure 5. Turn-Off Time

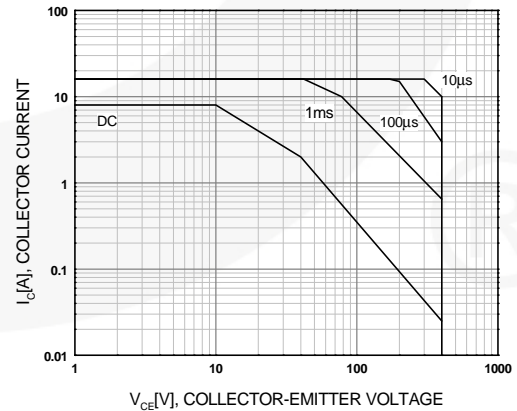


Figure 6. Forward Biased Safe Operating Area

Typical Performance Characteristics (Continued)

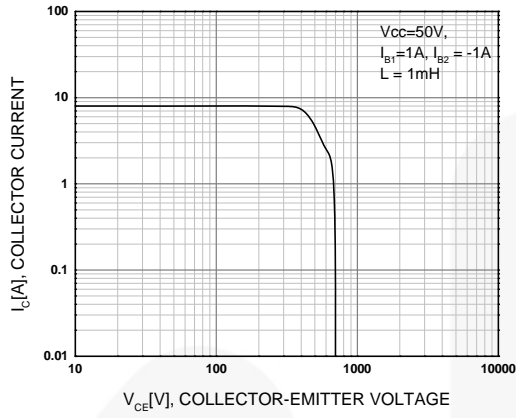


Figure 7. Reverse Biased Safe Operating Area

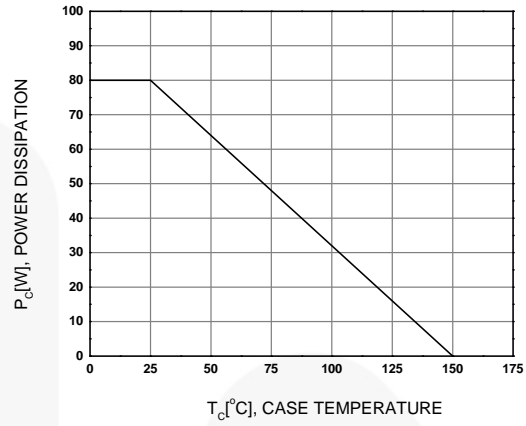


Figure 8. Power Derating





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